	Тур е	ь#	Hit s	Search Text	DBs	Time Stam P	Comments	fi	Errors
1	IS& R	L1	410 9	((359/290,291,295,298,302,31 1) or (73/720,721,722,723,715) or (216/2) or (438/53)).CCLS.	USP AT; US- PGP UB	2004 /08/ 11 13:2 5			0
2	BRS	L8	189	1 and @pd>20040401	US-	2004 /08/ 11 13:3			0
3	BRS	L9	141	8 and (sacrificial\$3 or psg or (phosposilicate adj glass) or polysilicon or silicon)	AT; US-	2004 /08/ 11 13:3			0
4	BRS	L10	27	9 and transduc\$4		2004 /08/ 11 13:3			0
5	BRS	L12	17	10 and (diaphragm or (silicon adj1 nitride) or (silicon adj1 dioxide))	AT; US-	2004 /08/ 11 13:3			0
6	BRS	L14	12	12 and ((remov\$4 or etch\$4) near3 (sacrificial\$3 or psg or (phosposilicate adj glass) or polysilicon or silicon)	AT; US-	2004 /08/ 11 13:3 2			0
7	BRS	L16	6	13 and void\$3	AT; US-	2004 /08/ 11 13:3 2			0
8	BRS	L13	15	12 and ((remov\$4 or etch\$4) with (sacrificial\$3 or psg or (phosposilicate adj glass) or polysilicon or silicon)	USP AT; US- PGP UB	2004 /08/ 11 14:3 2			0
9	BRS	L20	0	12 and (re-flow\$4)	USP AT; US- PGP UB				0

	Тур е	L #	Hit s	Search Text	DBs	р	Comments	 Enrons
10	BRS	L19	5	12 and (reflow\$4)	AT; US-	2004 /08/ 11 14:3		0
11	BRS	L21	3	12 and (phosphosilicate or psg)	AT; US-	2004 /08/ 11 14:3		0
12	BRS	L22	3	12 and (phosphosilicate or psg or (phosphor with silicate\$2))	AT; US-	2004 /08/ 11 14:3		0

	Тур	L #	Hi ts	Search Text	DBs	Time Stam P	Connents	EnnorDeninition	Errors
1	BRS	L27	13 60 5	(mems or (micro-electromechanic\$4) or (micro adj electr\$4 adj mechanic\$4))	JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:1 5			0
2	BRS	L28	21 20	27 and @pd>20040401	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:1 6			0
3	BRS	L29	12 76	28 and (sacrificial\$3 or psg or (phosphosilicate adj glass) or polysilicon or (phosphor near3 silicate) or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:1 7			0
4	BRS	L30	52 9	29 and (diaphragm or (silicon adj1 nitride) or (silicon adj1 dioxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:1			0
5	BRS	L31	14 9	30 and transduc\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:1 7			0
6	BRS	L32	11	31 and ((remov\$4 or etch\$4) with (sacrificial\$3 or psg or (phosphosilicate adj glass) or (phosphor near2 silicate) or polysilicon or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:2			0
7	BRS	L33	26	32 and void\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004 /08/ 11 15:2 2			0